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Reaction kinetics and isotope effect of water formation by the surface reaction of solid H₂O₂ with H atoms at low temperatures

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We performed laboratory experiments on the formation of water and its isotopologues by surface reactions of hydrogen peroxide (H₂O₂) with hydrogen (H) atoms and their deuterated counterparts (D₂O₂, D) at 10–30 K. High-purity H₂O₂ (>95%) was prepared *in situ* by the codeposition of molecular oxygen and H atoms at relatively high temperatures (45–50 K). We determined that the high-purity H₂O₂ solid reacts with both H and deuterium (D) atoms at 10–30 K despite the large activation barriers (~2000 K). Moreover, the reaction rate for H atoms is approximately 45 times faster than that for D atoms at 15 K. Thus, the observed large isotope effect indicates that these reactions occurred through quantum tunneling. We propose that the observed HDO/H₂O ratio in molecular clouds might be a good tool for the estimation of the atomic D/H ratio in those environments.

Introduction

Water (H₂O) is the predominant solid constituent of icy layers of submicron-sized interstellar grains. Because of the potential importance of H₂O for chemical evolution in molecular clouds (MCs), elucidating the formation mechanism of H₂O in those environments is important. Although H₂O formation is possible by gas phase reactions at low temperatures,¹ the observed large abundance of H₂O cannot be explained only by the gas-phase synthesis.² Therefore, it is generally accepted that grain-surface reactions are crucial for producing H₂O in MCs.

Tielens and Hagen³ proposed that H₂O formation is initiated by hydrogenation of atomic oxygen (O), molecular oxygen (O₂), and ozone (O₃), and is completed by the following reactions:

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Since reaction (1) is a radical–radical reaction, it should proceed immediately once reactants encounter each other on the surface. This reaction has been studied experimentally by several groups.^{4–7} In contrast to reaction (1), reactions (2) and (3) have large activation barriers (>2000 K) in the gas phase.^{8,9} However, despite such a large barrier, these two reactions were proposed to contribute significantly to H₂O formation in dense MCs.¹⁰ Since reactions having such large barriers do not occur thermally in MCs, reactions (2) and (3) require quantum tunneling. The quantum tunneling rate k_q is expressed by the following equation, assuming a rectangular activation barrier with a height E_a and width a :¹¹

$$k_q \approx \nu_0 \exp[-(2a/\hbar)(2mE_a)^{1/2}], \quad (4)$$

where ν_0 and m represent the frequency of harmonic motion and the mass of the reaction, respectively. Since temperature is not included in the equation, k_q does not depend on the reaction temperature. Further details about quantum tunneling reactions have been described elsewhere.^{11–14}

We have recently studied reaction (2) experimentally by the codeposition of nonenergetic OH with H₂ and isotopologues such as OD, HD, and D₂ on a substrate and determined that the reactions occur at 10 K.¹⁴ In addition, significant isotope effects were observed, and reactions of OH and OD abstracting a D atom from HD and D₂ were approximately ten times slower than those abstracting an H atom from H₂ and HD. This isotope effect can be explained by the difference in the effective mass of tunneling reactions.¹⁴

A number of research studies have been conducted on reaction (3). In these previous studies, O₂ was used as an initial reactant rather than hydrogen peroxide (H₂O₂), which was produced by the successive hydrogenation of O₂ as follows:

For example, Miyauchi *et al.*¹⁵ exposed solid O₂ layers to H or D atoms at 10 K and determined that (i) the rate of O₂ hydrogenation (reaction (5)) is equal to that of O₂ deuteration, (ii) the rate of reaction (3) is slower than that of reaction (5), and (iii) the rate of reaction (3) is eight times faster than that of the following isotopically substituted reaction (7):

Miyauchi *et al.* considered that the rate difference between reactions (3) and (7) would be due to the isotope effect of quantum tunneling.¹⁵ However, in the O₂ hydrogenation experiments, the formation of both H₂O₂ and H₂O occurs in the sample solid. Furthermore, the parent O₂ molecule is IR-inactive. Thus, multi-parameter fittings, which often cause significant errors, are necessary to obtain the rates for reactions (3) and (5). Moreover, recent studies suggested that H₂O may form by another exothermic reaction in typical experimental conditions for O₂ hydrogenation:^{16,17}

In addition to reaction (3), OH is expected to form by the following pathway:

where H_2O_2^* is a reaction intermediate. The reaction of two OH also yields H_2O_2 on the surface:

The branching ratio of barrierless reactions (8) to (10) was determined experimentally¹⁷ to be 1 to 4 at 40 K and theoretically¹⁸ to be 1 to 9 on a cold substrate. In any case, reactions (8) and (10) may compete during O_2 hydrogenation experiments to some extent, making it more difficult to obtain reliable kinetic parameters for reaction (3). In the case of CO hydrogenation experiments, a similar problem occurred because both formaldehyde (H_2CO) and methanol (CH_3OH) were produced in a single experiment.^{19–23} However, additional experiments using H_2CO as an initial reactant have enabled us to better understand the reaction kinetics and isotope effects of CO and H_2CO hydrogenation.^{13,24} Similarly, the use of H_2O_2 as an initial reactant is desirable for studying the kinetics and isotope effects of reaction (3). However, because of difficulty in using pure H_2O_2 , to date such an experiment has not been performed.

In the present study, we performed experimental studies on the formation of H_2O *via* reaction (3) and its isotope effect using high-purity (>95%) solid H_2O_2 and D_2O_2 .

Experimental

Apparatus and experimental conditions for water formation

All experiments were performed using the Apparatus for SURface Reaction in Astrophysics (ASURA) system. The ASURA primarily comprises a main chamber and an atomic source. An aluminum (Al) substrate was mounted at the center of the main chamber and all reactions were performed on the substrate at 10–30 K. Hydrogen (H) and deuterium (D) atoms were produced by the dissociation of H_2 and D_2 molecules, respectively, in a microwave discharge plasma, and were cooled by multiple interactions with the inner wall of the aluminum pipe, which was cooled to 100 K. We confirmed that the formed H and D atoms were well thermalized to the pipe temperature.²⁵ Further details of the ASURA have been described elsewhere.^{25,26}

The fluxes of H and D atoms were not directly measured in the present experimental setup; they were estimated by comparing the effective rates of CO hydrogenation and deuteration with those reported by Hidaka *et al.*,²⁷ which were obtained under the same experimental conditions. Briefly, amorphous H_2O ice ($\alpha\text{-H}_2\text{O}$) with a thickness of approximately ten monolayers (ML; $\sim 10^{15}$ molecules cm^{-2}) was produced by vapor deposition on the substrate at 15 K, followed by the deposition of CO with a thickness of ~ 0.8 ML. The column density of H_2O and CO was calculated from the peak area and the previously published band strengths, as described by Hidaka *et al.*²⁷ The band strengths for the CO stretching of CO and OH

stretching of H_2O are 2.0×10^{-16} and 1.1×10^{-17} cm molecules $^{-1}$, respectively.²⁸ The obtained effective rates were 1.4 and 0.21 min $^{-1}$ for the hydrogenation and deuteration of CO, respectively (see Results section below for the determination of effective rate constants). These values are a factor of 3.3 and 6.4 larger than the effective rates of CO hydrogenation and deuteration, respectively, compared to those reported by Hidaka *et al.*,²⁷ whose fluxes of both H and D atoms were 2.6×10^{14} atoms cm $^{-2}$ s $^{-1}$. Assuming that the surface density of H and D atoms correlates linearly with their fluxes, the fluxes of H and D atoms in the present study were estimated to be 8.7×10^{14} and 1.7×10^{15} atoms cm $^{-2}$ s $^{-1}$, respectively, which corresponds to a D and H atom flux ratio of ~ 2 . The variations in the H and D fluxes are expected to be less than 10% during and between each experiment.

Approximately 1 ML of solid H_2O_2 or its deuterated counterpart D_2O_2 was produced on the substrate by the procedures shown in the next section. H_2O_2 and D_2O_2 were exposed to H (D) atoms at 10–30 K. Reaction products were monitored *in situ* by a reflection absorption Fourier Transform Infrared (FTIR) spectrometer with a resolution of 4 cm $^{-1}$ in the spectral range from 700 to 4000 cm $^{-1}$. The column density of H_2O_2 and D_2O_2 was calculated from the peak area and previously published band strengths.¹⁵ The band strengths used were 2.1×10^{-17} and 1.5×10^{-17} cm molecule $^{-1}$ for the OH and OD bending bands at 1385 and 1039 cm $^{-1}$, respectively.

Experiments were also performed on an amorphous D_2O ice (a- D_2O ; ~ 30 ML) vapor-deposited at 10 K. The band strength used was 1.3×10^{-16} cm molecule $^{-1}$ for the OD stretching band.¹⁵

Preparation of high-purity solid hydrogen peroxide

In previous studies,^{29,30} high-purity H_2O_2 (>97%) has been prepared by distilling commercially available H_2O_2 solution under vacuum. The distilled H_2O_2 was introduced into a reaction substrate through a transfer line made with nonreactive materials such as glass to avoid the catalytic decomposition of H_2O_2 on metal surfaces. However, in a typical apparatus, which comprises a stainless steel chamber and gas lines, it is not easy to obtain pure H_2O_2 using this procedure without significant modification.

Thus, we produced high-purity solid H_2O_2 *in situ* by the codeposition of H atoms with O_2 molecules on a substrate at relatively high temperatures. In our previous study, we determined that H_2O_2 -rich ice tends to form by the O_2 /H codeposition at high temperatures (>30 K) and with an increasing proportion of O_2 relative to H atoms.³¹ For example, when O_2 and H were codeposited with an O_2 /H ratio of $\sim 2 \times 10^{-3}$ at 20 K, the main product was H_2O with a small amount of H_2O_2 ($\text{H}_2\text{O}/\text{H}_2\text{O}_2 \sim 5$). When the same experiment was performed with an O_2 /H ratio of $\sim 9 \times 10^{-3}$ at 40 K, the main product was H_2O_2 with $\sim 15\%$ contamination of H_2O . We further extended this experiment for the production of solid H_2O_2 with higher purity suitable for studying the kinetics and the isotope effect of reaction (3). One of the major advantages of this sample preparation method is that it is possible to study the isotope effect of reaction (3) using different isotopes (*i.e.*, H and D), which was not possible in previous studies.^{15,32}

Gaseous O_2 was introduced into the main chamber through a capillary plate. From the pressure inside the main chamber, the O_2 flux was estimated to be 1.0×10^{14} molecules cm $^{-2}$ s $^{-1}$, which is two to four orders of magnitude larger than

that used by Oba *et al.*³¹ The H atoms were codeposited with O₂ onto the substrate at 45–50 K. In the present experiments, pure H₂O₂ solid and the solid on a-D₂O were used as reactants. The amount of solid H₂O₂ was ~1 ML. After the formation of solid H₂O₂, the microwave was switched off, the supply of all gases (H₂ and O₂) was stopped, and the substrate temperature was raised to 70 K to remove residual O₂ from the sample solid. H₂O contamination in the solid H₂O₂ was <5%, which was confirmed by the IR spectrum of the product (Figure 1a). We believe that this small amount of contamination does not significantly impact the kinetics of reaction (3). We confirmed this by a temperature-programmed desorption experiment wherein little O₂ remained on the substrate after the sample treatment. The produced H₂O₂ was then cooled to the desired temperatures (10–30 K) for hydrogenation or deuteration experiments. Moreover, when D atoms were used, high-purity D₂O₂ was formed (Figure 1b).

Results

H₂O₂ + H and H₂O₂ + D

Figure 2 shows IR absorption spectra of solid H₂O₂ (top) and H₂O (bottom) for comparison and the difference spectra of 1 ML pure solid H₂O₂ after H atom exposure for up to 10 min at 15 K (middle). In the difference spectra, the peaks below and above the baseline represent decreases of initial reactant and increase of reaction products, respectively. With increasing H atom fluence, the peak intensity for the OH bending of H₂O₂ at 1385 cm⁻¹ decreased, and new peaks appeared at 3000–3600, 2850, and 1660 cm⁻¹. The peak at 1660 cm⁻¹ is attributable to the OH bending of H₂O formed by reaction (3). Based on the peak position of OH stretching bands of solid H₂O₂ and H₂O (Figure 2), the H₂O band at 3000–3600 cm⁻¹ has a substantial overlap with that of H₂O₂, and the peak shape would be attributable to the sum of H₂O₂ decrease and H₂O increase. In addition, H₂O₂ has another strong peak at 2827 cm⁻¹, which is often assigned to the $\nu_2 + \nu_6$ combination band.³³ If the amount of H₂O₂ decreases after H atom exposure, the intensity of the peak should also decrease. However, a peak was observed slightly above the baseline at 2850 cm⁻¹ after H atom exposure, unlike other peaks at ~3300 and 1385 cm⁻¹ (Figure 2). These apparently contradictory observations will be discussed later in the Discussion section. Two small peaks

Fig. 1 FTIR spectra of (a) H₂O₂ and (b) D₂O₂ produced at 45 K.

Fig. 2 FTIR spectra of H_2O_2 (top) and pure H_2O (bottom) and the variations in the difference spectra of H_2O_2 after exposure to H atoms for up to 10 min at 15 K (middle).

appeared at 3697 and 3721 cm^{-1} after H atom exposure (Figure 2), which are attributed to the 3- and 2-coordinated water molecules, respectively.³⁴

Figure 3 shows the difference spectra of 1 ML H_2O_2 after D atom exposure for up to 120 min at 15 K. If H_2O_2 reacts with D atoms, HDO is expected to form as a main product by the following reaction:

After D atom exposure to H_2O_2 , the peak area for OH stretching and bending bands decreased. New peaks appeared at 3490 , 2527 , and 1492 cm^{-1} , which are

Fig. 3 Variations in the difference spectra of H_2O_2 after exposure to D atoms for up to 120 min at 15 K.

typically observed for solid HDO at low temperatures.^{35,36} This result clearly indicates that HDO was formed by reaction (11) at 15 K. Although the peak area for OH stretching and bending bands decreased after D atom exposure, the $\nu_2 + \nu_6$ combination band at 2860 cm^{-1} increased slightly. Very small peaks appeared at 2722 and 3693 cm^{-1} after D atom exposure (Figure 3), the former of which is probably derived from the dangling OD bond of HDO.³⁷ The latter peak could be the dangling OH bond of HDO; however, the assignment is uncertain because of low S/N.

Figure 4 plots variations in the column density of solid H_2O_2 normalized to the unexposed initial amount after exposure to H or D atoms. We fitted the plots in Figure 4 to the following single-exponential decay function to obtain the kinetic parameters for reactions (3) and (11):

$$\Delta[\text{H}_2\text{O}_2]/[\text{H}_2\text{O}_2]_0 = A(e^{-k_n[X]t} - 1), \quad (12)$$

where A is a saturation value, t is the H or D atom exposure time, k_n is the rate constant of reaction (n), and $[X]$ is the number density of X atoms ($X = \text{H}$ or D) on the surface. Unfortunately, it is difficult to measure $[X]$ in the present experiment; thus, the product $k_n[X]$ is obtained as a fitting parameter for equation (12). Hereafter, $k_n[X]$ is denoted as the effective rate constant k'_n in the present study. We assume that during exposure, $[X]$ is independent of time and is governed mainly by the balance between the flux of X atoms, the sticking coefficient of the impinging atoms, and the loss of atoms by X–X recombination. We obtained $k'_3 = 7.2 \times 10^{-1}$ and $k'_{11} = 3.2 \times 10^{-2}\text{ min}^{-1}$ at 15 K, and the k'_3/k'_{11} ratio was 23.

In the present study, we do not determine the absolute yields of reaction products with the decrease in the column density of reactants, because the band strengths of the products (H_2O or HDO) have been reported only for a transmission method. Using these reported values may cause a large error ($<50\%$)³¹ when those band strengths are used in a reflection method. However, it does not

Fig. 4 Variations in the column density of H_2O_2 normalized to the initial amount as a function of exposure time of H or D atoms at 15 K. Solid lines are single-exponential decay fits to the plots.

affect the values of effective rate constants because the term of band strength is not included in equation (12). In addition, a portion of the reaction products could desorb from the substrate upon formation,^{38,39} making the interpretation of the yields of products more difficult.

D₂O₂ + H and D₂O₂ + D

Figure 5 shows variations in the difference spectra of pure solid D₂O₂ after exposure to H atoms on the Al substrate at 15 K. With increasing D atom fluence, the peak intensity of OD stretching and bending bands at 2467 and 1045 cm⁻¹, respectively, decreased, and new peaks appeared at 3455, 2587, and 1477 cm⁻¹. By comparing the peak positions with those given in the literature,³⁶ we determined that these new peaks are attributable to HDO, indicating that solid D₂O₂ reacted with H atoms to yield HDO at 15 K:

The peak intensity of the $\nu_2 + \nu_6$ combination band for D₂O₂ (2126 cm⁻¹)³³ increased slightly, which is opposite to the behavior that would be observed if D₂O₂ was consumed by reaction (13). The dangling OH band of HDO was observed at 3694 cm⁻¹ while the dangling OD band was not confirmed probably due to low S/N (Figure 5).

Figure 6 shows variations in the difference spectra after D atom exposure to D₂O₂ for up to 120 min at 15 K. This experiment was performed to study reaction (7):

This reaction has been studied in previous O₂ deuteration experiments.^{15,32} In the present study, with increasing D atom fluence, new peaks appeared at 2562 and

Fig. 5 Variations in the difference spectra of D₂O₂ after exposure to H atoms for up to 10 min at 15 K.

Fig. 6 Variations in the difference spectra of D_2O_2 after exposure to D atoms for up to 120 min at 15 K.

1220 cm^{-1} , concurrent with the decrease of D_2O_2 (Figure 6). The new peaks can be attributed to the OD stretching and bending of D_2O , which clearly indicates that reaction (7) occurred to yield D_2O on the surface at 15 K. A small peak was observed after exposure to D atoms at 2727 cm^{-1} , which is assigned to the 3-coordinated dangling OD band of D_2O .³⁴ A 2-coordinated dangling OD band (at 2748 cm^{-1})³⁴ was not firmly identified, probably due to the low S/N of the spectrum. The peak intensity of the $\nu_2 + \nu_6$ combination band for D_2O_2 increased as well (Figure 6).

Figure 7 shows variations in the column density of solid D_2O_2 normalized to the unexposed initial amount after H or D atom exposure at 15 K. The relative abundance of D_2O_2 by reaction (13) reaches a saturation value of approximately

Fig. 7 Variations in the column density of D_2O_2 normalized to the initial amount as a function of H or D atom exposure times at 15 K. Solid lines are single-exponential decay fits to the plots.

−0.2 after a few minutes. In contrast, the decrease of D_2O_2 by reaction (7) was much slower, reaching the almost same saturation value after 150 min. By fitting the plots in Figure 7 into single exponential decay function (12) where $[H_2O_2]$ is replaced with $[D_2O_2]$, we obtained $k_{13}' = 8.9 \times 10^{-1}$ and $k_7' = 2.3 \times 10^{-2} \text{ min}^{-1}$, and the k_{13}'/k_7' ratio was 38.

Reactions on amorphous D_2O ice

Hydrogenation and deuteration of solid H_2O_2 and D_2O_2 were also performed on vapor-deposited a- D_2O with a thickness of $\sim 30 \text{ ML}$ at 15 K. Figure 8 shows an IR spectrum of 1 ML solid H_2O_2 produced on a- D_2O and the difference spectra after H atom exposure for up to 5 min. The peak area of the $\nu_2 + \nu_6$ combination band before H atom exposure was larger by a factor of two than that on the Al substrate, although the peak area of other bands (OH stretching and bending) was almost equal.

With increasing H atom fluence, the intensities of peaks at 3233, 2852, and 1392 cm^{-1} decreased and new peaks appeared at 3422 and 1635 cm^{-1} . These observations clearly indicate that H_2O was formed by reaction (13). Notably, the peak intensity for the $\nu_2 + \nu_6$ combination band at 2852 cm^{-1} decreased after H atom exposure. This behavior is straightforward since H_2O_2 was consumed by reaction (13); however, interestingly, this is opposite to the result for the same reactions of pure H_2O_2 on the Al substrate described above. In addition to reaction (13), we confirmed in separate experiments that reactions (11), (13), and (7) occur on a- D_2O at 15 K. Two small peaks appeared at 3697 and 3719 cm^{-1} after exposure to H atoms (Figure 8), which are attributed to the 3- and 2-coordinated dangling OH bands, respectively.³⁴

We determined the effective rate constants with statistical errors for each reaction (Table 1) by fitting the attenuation of H_2O_2 and D_2O_2 into a single exponential decay function (12). As a general trend, values of k' are larger for reactions on a- D_2O .

Fig. 8 Variations in the difference spectra of H_2O_2 produced on a- D_2O for up to 5 min at 15 K.

Table 1 Effective rate constants with statistical errors determined in the present study at 15 K

Reaction	Reaction number	Substrate	Effective rate (min^{-1})	E_a (K) ^a	Reduced mass (u)
$\text{H}_2\text{O}_2 + \text{H}$	3	Al	$7.2 \pm 0.6 \times 10^{-1}$	2508	0.97
		a- D_2O	$9.9 \pm 0.6 \times 10^{-1}$		
$\text{H}_2\text{O}_2 + \text{D}$	11	Al	$3.2 \pm 0.1 \times 10^{-2}$	2355	1.89
		a- D_2O	$4.0 \pm 0.6 \times 10^{-2}$		
$\text{D}_2\text{O}_2 + \text{H}$	13	Al	$8.9 \pm 1.1 \times 10^{-1}$	2540	0.97
		a- D_2O	$9.2 \pm 0.6 \times 10^{-1}$		
$\text{D}_2\text{O}_2 + \text{D}$	7	Al	$2.3 \pm 0.2 \times 10^{-2}$	2384	1.89
		a- D_2O	$2.2 \pm 0.8 \times 10^{-2}$		

^a Taquet *et al.*⁴⁰

The column densities of H_2O formed on the Al and a- D_2O by reaction (3) were calculated using the band strength of the OH-bending at 1635 cm^{-1} ($1.2 \times 10^{-17} \text{ cm molecule}^{-1}$).²⁸ We determined that the H_2O yield on a- D_2O was approximately two orders of magnitude larger than that on the Al at the same H fluence, although the amount of H_2O_2 consumption on H atom exposure was identical for a- D_2O and Al (Figure 9).

Temperature dependence of reaction kinetics

Reaction (3) was studied using pure H_2O_2 at 10, 20, and 30 K as well as at 15 K. Reaction (3) occurred at all temperatures. We obtained kinetic parameters for reaction (3) (k_3') at each temperature following the procedures described above. Figure 10 shows variations in the relative abundance of pure H_2O_2 after H atom exposure at 10–30 K. The temperature dependence shows that the saturation value of H_2O_2 becomes larger with increasing temperature up to 20 K; however, at

Fig. 9 Variations in the column densities of H_2O (circle) and H_2O_2 (square) normalized to the initial H_2O_2 amount obtained after H atom exposure to H_2O_2 at 15 K. Open and filled symbols represent experimental results on a- D_2O and Al substrate, respectively.

Fig. 10 Variations in the column density of pure H_2O_2 normalized to the initial amount after exposure to H atoms at 10 (square), 15 (circle), 20 (triangle), and 30 (diamond) K. Lines are single-exponential decay fits to the plots.

30 K, the reaction is very slow and the saturation value is much less than that below 20 K. The effective rate constant is the largest at 10 K and decreases with increasing temperature. These features were also obtained for reactions on a- D_2O ice (Figure 11).

Discussion

Quantum tunneling and isotope effect

The reaction of H_2O_2 with H atoms and that of their deuterated counterparts has a large activation barrier (>2000 K) in the gas phase.^{9,40,41} Therefore, these reactions are expected to proceed through quantum tunneling at 10–30 K even on the

Fig. 11 Temperature dependence of the effective rate constant for reaction (3): filled circle and open square symbols represent the rate for pure H_2O_2 and H_2O_2 on a- D_2O , respectively.

surface, as mentioned earlier. A tunneling reaction strongly depends on the transmission mass of the activation barrier of reaction, as can be seen in equation (4). Theoretical studies proposed that H₂O formation by reaction (3) initiates from the formation of an intermediate by H atom addition to one O atom in H₂O₂, followed by the cleavage of the O–O bond.^{9,41} In general, the tunneling mass in the two-body addition reaction is described by the reduced mass μ .^{12,13} As shown in Table 1, the mass dependence of the reaction rate is evident; the lighter mass results in a faster reaction rate. Thus, we conclude that the reactions of H₂O₂/D₂O₂ with H/D atoms proceed by quantum tunneling.

The ratios of the effective rate constants between reactions (3) and (11) (k_3'/k_{11}') are 23 and 25 for pure H₂O₂ and H₂O₂ on a-D₂O, respectively. Since the effective rate constant k_n' is expressed as $k_n[X]$ where X = H or D, the ratio of the effective rate constants is not equal to the ratio of the actual reaction rate constants if $[H] \neq [D]$. Assuming that the value of $[X]$ has a linear correlation with the flux of X atoms in the present experiment, the ratios of k_3 to k_{11} (k_3/k_{11}) become 44 and 48 for pure H₂O₂ and H₂O₂ on a-D₂O, respectively, because the D atom flux is approximately twice that of the H atom flux. Similarly, the k_{13}/k_7 ratio was calculated to be 75 and 81 for pure D₂O₂ and D₂O₂ on a-D₂O, respectively. Taquet *et al.*⁴⁰ calculated a tunneling probability P_n through an Eckart potential barrier for reaction (n). In the present study, if we compare the P_3/P_{11} ratio with the k_3/k_{11} and the P_{13}/P_7 ratio with the k_{13}/k_7 , we obtain $k_3/k_{11} \sim 2 \times P_3/P_{11}$ and $k_{13}/k_7 \sim 3 \times P_{13}/P_7$. These differences are not surprising because the tunneling probability is significantly affected by the shape of the potential barrier, and it is very difficult to determine the tunneling rate with an accurate barrier for surface reactions. In fact, Taquet *et al.*⁴⁰ noted that, although the Eckart model provides a significant improvement over square barriers, which were typically used for this type of calculation, the tunneling probabilities of some reactions at low temperatures can be underestimated (or overestimated).

We obtained the k_3/k_7 ratios of 61 and 88 for pure H₂O₂/D₂O₂ and H₂O₂/D₂O₂ on a-D₂O, respectively. These values are about one order of magnitude larger than those reported by Miyauchi *et al.*, who determined the k_3'/k_7' ratio to be 8 in their O₂ hydrogenation/deuteration experiments at 10 K. Since the flux of H atoms was the same with that of D atoms in the previous experiment,¹⁵ the k_3'/k_7' ratio is certainly equal to the k_3/k_7 ratio on the assumption that the ratio of surface number densities between H and D atoms is same as that of the fluxes. The large difference may arise for several reasons. First, multi-parameter fittings may cause significant errors of k_3 and k_7 in their work. Second, H₂O and D₂O would form in O₂ hydrogenation/deuteration *via* separate pathways: OH + OH → H₂O + O and OD + OD → D₂O + O, respectively, which are both barrierless reactions. This would lead to an overestimation of the k_3/k_7 ratio. In the present study, these uncertainties are removed because H₂O₂ or D₂O₂ are used as the initial reactants. Thus, we believe that our calculated value of k_3/k_7 is more reliable than that obtained in O₂ hydrogenation/deuteration experiments.

Next, we compare the rates of reactions (3) and (5). The k_5/k_3 ratio in the O₂ hydrogenation experiment was reported to be 3.3.¹⁵ Based on the fact that reaction (5) is barrierless and reaction (3) has a large barrier (>2000 K),⁹ the value obtained by Miyauchi *et al.* seems to be rather small. Subsequently, we calculated the k_5/k_3 ratio using k_3' obtained in the present study. The value of k_5' reported by Miyauchi *et al.* (12.8 min^{−1})¹⁵ was not used for this calculation

because their conditions such as atom fluxes and sample amounts were significantly different from ours. Instead, we used the value of k_5' (5.2 min^{-1}) obtained in the following experiment: solid O_2 ($\sim 3 \text{ ML}$) on an amorphous D_2O ice (30 ML) was exposed to H atoms (flux: $2 \times 10^{14} \text{ atoms cm}^{-2} \text{ s}^{-1}$) at 10 K .⁴² After the correction of the flux difference, we obtained the k_5/k_3 ratio of ~ 15 , which is approximately five times larger than that reported by Miyauchi *et al.*¹⁵ Although the sample compositions and the fluxes of H atoms in these two experiments do not exactly match, we believe that the present result would better represent the k_5/k_3 ratio compared to previous studies.

Notably, the observed isotope effect in the hydrogen/deuterium addition to H_2O_2 (k_3/k_{11}) is much larger than that for one of the astrochemically-important tunneling surface reactions: the hydrogenation/deuteration of CO. Hidaka *et al.*²⁷ reported that the rate of CO hydrogenation (k_{H}) was larger than CO deuteration (k_{D}), with a $k_{\text{H}}/k_{\text{D}}$ ratio of 12.5. This isotope effect is approximately four times smaller than that of the hydrogenation/deuteration of H_2O_2 observed in the present study. This large difference is rather surprising because the barrier height for the hydrogenation/deuteration of H_2O_2 is similar to that of CO.^{40,43} We believe that the difference might have been due to accumulation of multiple factors such as differences in residence time of H/D atoms on H_2O_2 and CO and the shape of the potential barriers.

As mentioned previously, we assume that the surface density of H atoms is the same as that of D atoms when the flux is equal. However, in a series of experiments under high H and D flux conditions, this may not always be true. Even under the same flux conditions for H and D atoms, the surface density of D atoms ($[\text{D}]$) may become larger than that of H atoms ($[\text{H}]$). Since H atoms can diffuse faster on the surface than D atoms, the recombination probability for H atoms is higher than that for D atoms,¹² resulting in a lower value of $[\text{H}]$ than that of $[\text{D}]$ even under the same fluxes. In that case, the ratio of $[\text{H}]/[\text{D}]$ becomes smaller than 0.5, yielding larger values of k_3/k_{11} and k_{13}/k_7 than those reported in the present study. Further studies related to the surface densities of H and D atoms are necessary.

Dependence of reaction efficiency on temperature and type of substrate

The effective rate constants for reaction (3) decrease with increasing substrate temperature (Figure 11). This is opposite to the typical Arrhenius-type behavior where the reaction rate has a positive correlation with temperature. In addition, because reaction (3) occurred through quantum tunneling, the reaction rate should have lesser dependence on the surface temperatures. The decrease of the effective rate can be explained well by the decrease in the number density of H atoms on the surface with increasing temperature because the effective rate k_3' is expressed by $k_3[\text{H}]$. This trend was also observed in CO hydrogenation and deuteration, H_2CO hydrogenation, H–D substitution of CH_3OH , and O_2 hydrogenation on low-temperature surfaces.^{11,42}

The difference of the effective rate constant between reactions of pure H_2O_2 and H_2O_2 on a- D_2O is the largest at 10 K and decreases with increasing temperature (Figure 11). The large difference observed at lower temperatures ($< 15 \text{ K}$) may be explained by the difference in the number density of H atoms on the surface because a- D_2O would have a much larger surface area compared to planar Al

substrate, as reported for CO hydrogenation by Hidaka *et al.*⁴⁴ who determined that the surface area for a-H₂O with thickness equivalent to ~ 17 ML is approximately nine times larger than that for crystalline H₂O. In contrast, at elevated temperatures where the residence time of H atoms on the surface is very short even on a-D₂O, the difference could little be affected by the density of H atoms, which can lead to similar effective rate constant values under both conditions (Figure 11).

In Figure 9, H₂O yield for the sample of pure H₂O₂ on Al substrate is lower than that for H₂O₂ on a-D₂O, although the decrease of H₂O₂ is approximately the same for both samples. This difference may be partly explained by immediate desorption of H₂O formed as a product at the reaction preferentially occurred on the Al substrate. This behavior is also observed in O₂ + D experiments on amorphous silicates and a-H₂O, where the yield of D₂O is higher for reactions on a-H₂O.³⁹ The heat of reaction (3) ($285 \text{ kJ mol}^{-1} = 2.9 \text{ eV}$) is partly partitioned to the reaction product H₂O and OH. This energy would be sufficient for H₂O to desorb from the substrate (Al or a-D₂O). For the H₂O₂ on a-D₂O sample, interaction of H₂O₂ and H₂O product with the a-D₂O surface is much stronger than that with the Al surface because of hydrogen bonding. Therefore, the reaction heat can dissipate into a-D₂O more easily, and desorption at the reaction surface may be reduced. Furthermore, since a-D₂O has a large surface area because of pores and cracks, the desorbed H₂O can be retrapped on the surface of a-D₂O. This type of H₂O relaxation and trap has been demonstrated both experimentally^{45–47} and theoretically^{48,49} to occur during the photodesorption of H₂O from bulk a-H₂O. In addition to H₂O, OH should also form by reaction (3) and can be the source of another H₂O formation. Accordingly, H₂O and OH trapped on the surface of a-D₂O may explain the larger column density of the formed H₂O than that on the Al substrate (Figure 9).

As shown in Figure 1, solid H₂O₂ produced on the Al substrate has representative strong absorptions at three positions: $1385 (\nu_2)$, $2827 (\nu_2 + \nu_6)$, and $3326 \text{ cm}^{-1} (\nu_1)$.³³ Similarly, for solid H₂O₂ on a-D₂O, these three peaks are slightly shifted on the spectrum at 1392 , 2852 , and 3233 cm^{-1} (Figure 8). The difference in the peak position for each band is not very large ($< 25 \text{ cm}^{-1}$). However, the peak area of the $\nu_2 + \nu_6$ combination band was larger by a factor of two for the sample on a-D₂O, although the peak area of other bands (ν_1 and ν_2) was identical on both substrates. A relatively strong peak at $\sim 2850 \text{ cm}^{-1}$ for solid H₂O₂ is typically assigned to the $\nu_2 + \nu_6$ combination band;^{33,50} however, some studies considered that this assignment is disputable.^{51,52} Ignatov *et al.*⁵¹ proposed that this peak is attributable to an OH valence band of the H₂O₂ molecule placed in the unusual surface environment. The present results imply that the peak intensity at $\sim 2850 \text{ cm}^{-1}$ might correlate with the configuration of H₂O₂ on the substrate. In addition, the fact that H₂O₂ forms hydrogen bonds more on a-D₂O than on Al could result in the different IR features at $\sim 2850 \text{ cm}^{-1}$. In other words, the number of hydrogen bonds between H₂O₂ and surrounding H₂O may constrain the peak intensity at $\sim 2850 \text{ cm}^{-1}$. If this is the case, it could explain the contradictory behavior of the peak intensity after exposure to atoms (*e.g.* Figures 2 and 8). More detailed experimental and theoretical studies are necessary for the precise peak assignment. Thus, we propose that care should be taken when this IR peak is used for quantification of solid H₂O₂ in various environments.

Dangling OH (OD) bands of reaction products

We confirmed that the formed solid H₂O and its isotopologues (HDO and D₂O) show the dangling OH (OD) bands (*e.g.*, Figure 2). The presence of dangling OH bands in the IR spectrum of solid H₂O typically indicates that it is amorphous and has a microporous structure.³⁴ However, we have reported that dangling OH bands are not observed in solid H₂O formed by codeposition of O₂ and H atoms at 10 K and that the formed ice is amorphous but has a compact structure.³¹ These different results suggest that the formed ice structure depends on experimental conditions and that the properties of the reaction products are strikingly different between each study (multilayers with O₂ contaminants *vs.* very thin layers with little contaminants).

Astrophysical implication

Deuterated water (HDO and D₂O) has been identified in the gas phase with HDO/H₂O and D₂O/H₂O ratios up to the order of 10^{−2} and 10^{−3}, respectively, toward protostars.^{53–57} In contrast, deuterated water was not clearly identified in the solid phase; only the upper limit of HDO was determined (HDO/H₂O < 0.2%–2%).^{58,59} Despite the detection of deuterated water in the gas phase only, it is reasonable to consider that deuterated water is also produced by surface reactions on interstellar grains at very low temperatures.

The following reactions are possible to yield water isotopologues from H₂O₂ and its isotopologues:

We did not study reactions (14) and (15) because of difficulty in producing high-purity HDO₂. Two types of reaction products are possible for reactions (14) and (15). Since the reduced mass of a reaction to produce the intermediate does not depend on the type of products, we expect that reactions (14a) and (14b) occur to the same extent statistically. In fact, the tunneling probability for reaction (14a) is calculated to be identical with that of reaction (14b).⁴⁰ The same is true for reactions (15a) and (15b). Thus, for simplicity, we made a rough assumption based on the obtained results that H atom addition reactions such as reactions (3) and (13) occur faster by a factor of 50 than D atom addition reactions such as reactions (7) and (11). In addition, we assume that the atomic D/H ratio is

constant and the surface diffusion rates of H and D atoms are the same. Under these assumptions, we determined that the HDO/H₂O ratio was almost identical to the atomic D/H ratio, while the D₂O formation was negligible ($\sim 10^{-6}$ that of H₂O). On the other hand, assuming no isotope effect on the reactions, the HDO/H₂O ratio becomes twice as large as the atomic D/H ratio; thus, quantum tunneling would cause a decrease of the HDO/H₂O ratio in this reaction pathway. In other words, if quantum tunneling corrections are not included in a chemical model, the obtained result should overestimate the value of the HDO/H₂O ratio.

We extend this discussion to other water formation pathways, *i.e.*, reactions (1) (OH + H → H₂O) and (2) (OH + H₂ → H₂O + H). For reaction (2), we have experimentally determined the relative efficiency of reactions for all possible isotopologues;¹⁴ H atom abstraction reactions are approximately ten times more efficient than D atom abstraction reactions. Assuming that OH and OD are formed by surface reactions O + H and O + D, respectively, HD/H₂ ratio is 10^{-5} , and no D₂ is present, the HDO/H₂O ratio was very much consistent with the atomic D/H ratio.

In contrast to the former two reaction pathways, the reactions of OH or OD with H or D atoms do not have an activation barrier. Thus, the product ratio would strongly depend on the atomic D/H ratio. Since there are two possible reactions to yield HDO (OH + D → HDO and OD + H → HDO), statistically the HDO/H₂O ratio is twice as large as the atomic D/H ratio. With regard to the formation of D₂O, this reaction pathway is the most favorable among the three reaction pathways; the D₂O/H₂O ratio is statistically the square of the value of the D/H ratio. For example, the D₂O/H₂O ratio is 10^{-4} if the atomic D/H is 10^{-2} . This value is two to four orders of magnitude higher than that estimated by other pathways under the same assumptions. Therefore, the OD + D reaction is the only possible pathway to effectively yield D₂O in MCs.

Moreover, it is important to note that, on grain surfaces, the deuterium fractionation of water occurs only during the formation by surface reactions at the typical temperature of MCs (~ 10 K). This is supported by the fact that H₂O does not react with D atoms at < 15 K⁶⁰ and thermal H–D exchange does not occur at < 100 K,⁶¹ which prevents the D-enrichment by H–D substitution with other deuterium-enriched species after the formation of H₂O on the grains. The reactivity of water with D atoms at low temperatures differs from that of organic species such as CH₃OH,^{25,60} H₂CO,^{13,27} and CH₃NH₂⁶² where H–D exchange occurs for these molecules by reacting with D atoms at temperatures as low as 10 K.

Based on the present and previous experimental results for water formation, we suggest that the HDO/H₂O ratio might be a key parameter to estimate the atomic D/H ratio during the formation of water. Namely, the following relationship is roughly derived from experimental studies: $(D/H)_{\text{atom}} \leq (HDO/H_2O) \leq 2(D/H)_{\text{atom}}$ or $1/2(HDO/H_2O) \leq (D/H)_{\text{atom}} \leq (HDO/H_2O)$, where $(D/H)_{\text{atom}}$ and (HDO/H_2O) represent the atomic D/H on grains and the HDO/H₂O ratio formed by surface reactions, respectively. Note that these relationships were derived with reference to experimental studies for surface reactions. In addition to surface reactions, deuterium fractionation of water by gas phase reactions may also be possible.⁶³ Moreover, energetic processes induced by UV and cosmic rays might cause hydrogen isotopic fractionation of water during its decomposition and interactions with other ice components, both of which may modify the HDO/H₂O ratio. Therefore, we propose that further collaborative theoretical and

experimental studies on surface and gas phase chemistries are necessary to construct a complete chemical model regarding the evolution of the water D/H ratio in MCs.

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